2.5V and 3.3V LVCMOS Clock Distribution Buffer

Features

- Configurable 10 outputs LVCMOS clock distribution buffer
- Compatible to single, dual and mixed 3.3V/2.5V
 Voltage supply
- Wide range output clock frequency up to 250MHz
- Designed for mid-range to high-performance telecom, networking and computer applications
- Supports applications requiring clock redundancy
- Max. output skew of 200pS (150pS within one bank)
- Selectable output configurations per output bank
- Tristatable outputs
- 32 lead LQFP & TQFP Packages
- Ambient operating temperature range of -40 to 85°C

Functional Description

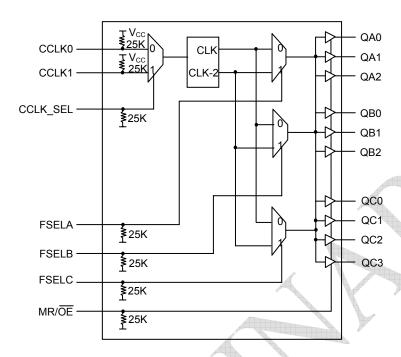
The ASM2I99446 is a 2.5V and 3.3V compatible 1:10 clock distribution buffer designed for low-voltage mid-range to high-performance telecom, networking and computing applications. Both 3.3V, 2.5V and dual supply voltages are supported for mixed-voltage applications. The ASM2I99446 offers 10 low-skew outputs and 2 selectable inputs for clock redundancy. The outputs are configurable and support 1:1 and 1:2 output to input frequency ratios. The ASM2I99446

is specified for the extended temperature range of -40°C to 85°C.

The ASM2I99446 is a full static fanout buffer design supporting clock frequencies up to 250MHz. The signals are generated and retimed on-chip to ensure minimal skew between the three output banks. Two independent LVCMOS compatible clock inputs are available. This feature supports redundant clock sources or the addition of a test clock into the system design. Each of the three output banks can be individually supplied by 2.5V or 3.3V supporting mixed voltage applications. The FSELx pins choose between division of the input reference frequency by one or two. The frequency divider can be set individually for each of the three output banks. The ASM2I99446 can be reset and the outputs are disabled by deasserting the MR/OE pin (logic high state). Asserting MR/OE will enable the outputs.

All inputs accept LVCMOS signals while the outputs provide LVCMOS compatible levels with the capability to drive terminated 50Ω transmission lines. Please consult the ASM2I99456 specification for a 1:10 mixed voltage buffer with LVPECL compatible inputs. For series terminated transmission lines, each of the ASM2I99446 outputs can drive one or two traces giving the devices an effective fanout of 1:20. The device is packaged in a $7x7mm^2$ 32-lead LQFP and TQFP Packages.

rev 0.4 Block Diagram



Pin Configuration

32 - LEAD PACKAGE PINOUT -- Top View

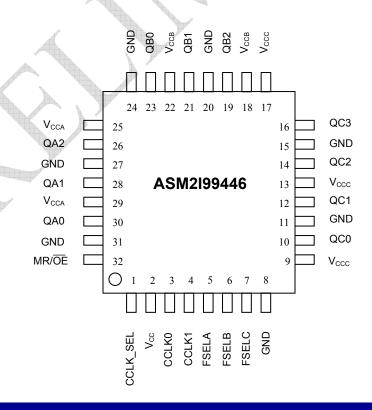


Table 1: Pin Configuration

Pin Number	Pin	I/O	Type	Function
3,4	CCLK0, CCLK1	Input	LVCMOS	LVCMOS clock inputs
5,6,7	FSELA, FSELB, FSELC	Input	LVCMOS	Output bank divide select input
32	MR/ŌĒ	Input	LVCMOS	Internal reset and output (high impedance) control
8,11,15,20,24,27,31	GND	-	Supply	Negative voltage supply (GND)
25,29 18,22 9,13,17	V _{CCA} , V _{CCB} , V _{CCC}	-	Supply	Positive voltage supply for output banks
2	V _{CC}	-	Supply	Positive voltage supply for core (V _{CC})
30,28, 26	QA0 - QA2	Output	LVCMOS	Bank A outputs
23,21,19	QB0 - QB2	Output	LVCMOS	Bank B outputs
10,12,14,16	QC0 - QC3	Output	LVCMOS	Bank C outputs

Note: $V_{\text{\tiny CCB}}$ is internally connected to $V_{\text{\tiny CC}}.$

Table 2: Supported Single and Dual Supply Configurations

Supply voltage configuration	V _{cc} ¹	V _{CCA} ²	V _{CCB} ³	V _{CCC} ⁴	GND			
3.3V	3.3V	3.3V	3.3V	3.3V	0V			
Mixed voltage supply	3.3V	3.3V or 2.5V	3.3V	3.3V or 2.5V	0 V			
2.5V	2.5V	2.5V	2.5V	2.5V	0 V			

Note: 1 V_{CC} is the positive power supply of the device core and input circuitry. V_{CC} voltage defines the input threshold and levels 2 V_{CCA} is the positive power supply of the bank A outputs. V_{CCA} voltage defines bank A output levels 3 V_{CCB} is the positive power supply of the bank B outputs. V_{CCB} voltage defines bank B output levels. V_{CCB} is internally connected to V_{CC}.

4 V_{CCC} is the positive power supply of the bank B outputs. V_{CCC} voltage defines bank C output levels.

Table 3: Function Table (Controls)

Control	Default	0	1
CCLK_SEL 0 CCLK0		CCLK0	CCLK1
FSELA 0 f _{QA0:2} =		$f_{QA0:2} = f_{REF}$	$f_{QA0:2} = f_{REF} \div 2$
FSELB	0	$F_{QBO:2} = f_{REF}$	$f_{QBO:2} = f_{REF} \div 2$
FSELC	0	$F_{QCO:3} = f_{REF}$	$f_{QCO:3} = f_{REF} \div 2$
MR/ŌĒ	0	Outputs enabled	Internal reset Outputs disabled (tristate)

Table 4: Absolute Maximum Ratings¹

Symbol	Characteristics	Min	Max	Unit	Condition
Vcc	Supply Voltage	-0.3	3.6	V	
V_{IN}	DC Input Voltage	-0.3	V _{CC} +0.3	V	
V_{OUT}	DC Output Voltage	-0.3	V _{CC} +0.3	V	
I _{IN}	DC Input Current		±20	mA	
I _{OUT}	DC Output Current		±50	mA	
Ts	Storage temperature	-65	125	°C	

Note: 1 These are stress ratings only and are not implied for functional use. Exposure to absolute maximum ratings for prolonged periods of time may affect device reliability.



Table 5: General Specifications

Symbol	Characteristics	Min	Тур	Max	Unit	Condition
V_{TT}	Output Termination Voltage		V _{CC} ÷2		V	
MM	ESD Protection (Machine Model)	200			V	
НВМ	ESD Protection (Human Body Model)	2000			V	
LU	Latch–Up Immunity	200			mA	
C _{PD}	Power Dissipation Capacitance		10		pF	Per output
C _{IN}	Input Capacitance		4.0		pF	

Table 6: DC CHARACTERISTICS ($V_{CC} = V_{CCA} = V_{CCB} = V_{CCC} = 3.3V \pm 5\%$, $T_A = -40^{\circ}C$ to +85°C)

Symbol	Characteristics	Min	Тур	Max	Unit	Condition
V_{IH}	Input High Voltage	2.0		$V_{CC} + 0.3$	>	LVCMOS
V_{IL}	Input Low Voltage	-0.3		0.8	V	LVCMOS
I _{IN}	Input Current ¹			200	μΑ	V _{IN} =GND or V _{IN} =V _{CC}
V_{OH}	Output High Voltage	2.4			V	I_{OH} =-24 mA ²
V _{OL}	Output Low Voltage			0.55 0.30	V	I_{OL} = 24mA ³ I_{OL} = 12mA
Z _{OUT}	Output Impedance	P	14 - 17		Ω	
I _{CCQ} ³	Maximum Quiescent Supply Current	A		2.0	mA	All V _{CC} Pins

Note: 1 Input pull-up / pull-down resistors influence input current.

2 The ASM2!99446 is capable of driving 50Ω transmission lines on the incident edge. Each output drives one 50Ω parallel terminated transmission line to a termination voltage of V_{TT}. Alternatively, the device drives up to two 50Ω series terminated transmission lines.

3 I_{CCQ} is the DC current consumption of the device with all outputs open and the input in its default state or open.



Table 7: AC CHARACTERISTICS $(V_{CC} = V_{CCA} = V_{CCB} = V_{CCC} = 3.3V \pm 5\%, T_A = -40^{\circ}C \text{ to } +85^{\circ}C)^{1}$

Symbol	Characteristics		Min	Тур	Max	Unit	Condition
f_{ref}	Input Frequency		0		250 ²	MHz	
f _{MAX}	Maximum Output Frequency	÷1 output ÷2 output	0 0		250 ² 125	MHz MHz	FSELx=0 FSELx=1
t _P , _{REF}	Reference Input Pulse Width		1.4			nS	A
t _r , t _f	CCLK Input Rise/Fall Time				1.0 ³	nS	0.8 to 2.0V
t _{PLH}	Propagation delay	CCLK0,1 to any Q CCLK0,1 to any Q	2.2 2.2	2.8 2.8	4.45 4.2	nS nS	
t _{PLZ, HZ}	Output Disable Time				10	nS	
t _{PZL, LZ}	Output Enable Time				10	nS	
t _{sk(O)}	Output-to-output Skew Within one bank Any output Bank, Same output divider Any output, Any output divider				150 200 350	pS pS pS	
t _{sk(PP)}	Device-to-device Skew	-			2.25	nS	
t _{SK(P)}	Output pulse skew ⁴		A		200	pS	
DCQ	Output Duty Cycle	÷1 output ÷2 output	47 45	50 50	53 55	% %	DC _{REF} = 50% DC _{REF} = 25%-75%
t _r , t _f	Output Rise/Fall Time		0.1		1.0	nS	0.55 to 2.4V

Note: 1 AC characteristics apply for parallel output termination of 50Ω to V_{TT}

Table 8: DC CHARACTERISTICS ($V_{CC} = V_{CCA} = V_{CCB} = V_{CCC} = 2.5V \pm 5\%$, $T_A = -40^{\circ}C$ to +85°C)

Symbol	Characteristics	Min	Тур	Max	Unit	Condition
V_{IH}	Input High Voltage	1.7		V _{CC} + 0.3	V	LVCMOS
V_{IL}	Input Low Voltage	-0.3		0.7	V	LVCMOS
V _{OH}	Output High Voltage	1.8			V	I _{OH} =-15 mA ¹
V _{OL}	Output Low Voltage			0.6	V	I _{OL} = 15 mA
Z _{OUT}	Output Impedance		17 - 20 ²		Ω	
I _{IN}	Input Current ²			±200	μA	V _{IN} =GND or V _{IN} =V _{CC}
I _{CCQ} ³	Maximum Quiescent Supply Current			2.0	mA	All V _{CC} Pins

Note: 1 The ASM2I99446 is capable of driving 50Ω transmission lines on the incident edge. Each output drives one 50Ω parallel terminated transmission line to a termination voltage of V_{TT} . Alternatively, the device drives up to two 50Ω series terminated transmission lines per output.

² The ASM2I99446 is functional up to an input and output clock frequency of 350MHz and is characterized up to 250MHz.

³ Violation of the 1.0nS maximum input rise and fall time limit will affect the device propagation delay, device-to-device skew, reference input pulse width, output duty cycle and maximum frequency specifications.

⁴ Output pulse skew is the absolute difference of the propagation delay times | t_{pLH} - t_{pHL} |.

² Input pull-up / pull-down resistors influence input current.
3 Icco is the DC current consumption of the device with all outputs open and the input in its default state or open.



Table 9: AC CHARACTERISTICS ($V_{CC} = V_{CCA} = V_{CCB} = V_{CCC} = 2.5V \pm 5\%$, $T_A = -40$ °C to +85°C)^{1,2}

Symbol	Characteristics		Min	Тур	Max	Unit	Condition
f _{ref}	Input Frequency		0		250 ³	MHz	
f _{MAX}	Maximum Output Frequency	÷1 output ÷2 output	0		250 ² 125	MHz MHz	FSELx=0 FSELx=1
t _P , _{REF}	Reference Input Pulse Width		1.4			nS	A
t _r , t _f	CCLK Input Rise/Fall Time				1.0 ⁴	nS	0.7 to 1.7V
t _{PLH} t _{PHL}	Propagation delay	CCLK0,1 to any Q CCLK0,1 to any Q	2.6 2.6		5.6 5.5	nS nS	
t _{PLZ, HZ}	Output Disable Time				10	nS	
t _{PZL, LZ}	Output Enable Time				10	nS	
t _{sk(O)}	Output-to-output Skew Within one bank Any output Bank, Same output divider Any output, Any output divider				150 200 350	pS pS pS	
t _{sk(PP)}	Device-to-device Skew				3.0	nS	
t _{SK(P)}	Output pulse skew ⁵		A		200	pS	
DC_Q	Output Duty Cycle	÷1 or ÷2 output	45	50	55	%	DC _{REF} = 50%
t _r , t _f	Output Rise/Fall Time		0.1		1.0	nS	0.6 to 1.8V

Note: 1 AC characteristics apply for parallel output termination of 50Ω to $V_{\text{TT}}.$

- 2 AC specifications are design targets, final specification is pending device characterization.
- 3 The ASM2I99446 is functional up to an input and output clock frequency of 350MHz and is characterized up to 250MHz.

 4 Violation of the 1.0nS maximum input rise and fall time limit will affect the device propagation delay, device-to-device skew, reference input pulse width, output duty cycle and maximum frequency specifications.
- 5 Output pulse skew is the absolute difference of the propagation delay times: $|t_{pLH} t_{pHL}|$.

Table 10: AC CHARACTERISTICS $(V_{CC} = 3.3V + 5\%, V_{CCA}, V_{CCB}, V_{CCC} = 2.5V + 5\% \text{ or } 3.3V + 5\%, T_A = -40^{\circ}\text{C to } +85^{\circ}\text{C})^{1.2}$

Symbol	Characte	ristics	Min	Тур	Max	Unit	Condition
t _{sk(O)}		Within one bank Same output divider , Any output divider	d ^a		150 250 350	pS pS pS	
t _{sk(PP)}	Device-to-device Skew				2.5	nS	
t _{PLH,HL}	Propagation delay	CCLK0,1 to any Q		See 3.3V	table		
t _{SK(P)}	Output pulse skew ³				250	pS	
DCQ	Output Duty Cycle	÷1 or ÷2 output	45	50	55	%	DC _{REF} = 50%

Note: 1 AC characteristics apply for parallel output termination of 50Ω to V_{TT} .

- 2 For all other AC specifications, refer to 2.5V or 3.3V tables according to the supply voltage of the output bank.
- 3 Output pulse skew is the absolute difference of the propagation delay times: | t_{pLH} t_{pHL} |.

APPLICATIONS INFORMATION

Driving Transmission Lines

The ASM2I99446 clock driver was designed to drive high speed signals in a terminated transmission line environment. To provide the optimum flexibility to the user the output drivers were designed to exhibit the lowest impedance possible. With an output impedance of less than 20Ω the drivers can drive either parallel or series terminated transmission lines. In most high performance clock networks point-to-point distribution of signals is the method of choice. In a point-to-point scheme either series terminated or parallel terminated transmission lines can be used. The parallel technique terminates the signal at the end of the line with a 50Ω resistance to $V_{\rm CC} \div 2$.

This technique draws a fairly high level of DC current and thus only a single terminated line can be driven by each output of the ASM2I99446 clock driver. For the series terminated case however there is no DC current draw, thus the outputs can drive multiple series terminated lines. Figure 3. "Single versus Dual Transmission Lines" illustrates an output driving a single series terminated line versus two series terminated lines in parallel. When taken to its extreme the fanout of the ASM2I99446 clock driver is effectively doubled due to its capability to drive multiple lines

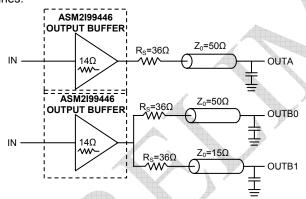


Figure 3. Single versus Dual Transmission Lines

The waveform plots in Figure 4. "Single versus Dual Line Termination Waveforms" show the simulation results of an output driving a single line versus two lines. In both cases the drive capability of the ASM2I99446 output buffer is more than sufficient to drive 50Ω transmission lines on the incident edge. Note from the delay measurements in the simulations a delta of only 43pS exists between the two differently loaded outputs. This suggests that the dual line driving need not be used exclusively to maintain the tight output-to-output skew of the ASM2I99446. The output waveform in Figure 4 "Single versus Dual Line Termination Waveforms" shows a step in the waveform. This step is caused by the

impedance mismatch seen looking into the driver. The parallel combination of the 36Ω series resistor plus the output impedance does not match the parallel combination of the line impedances. The voltage wave launched down the two lines will equal:

$$V_L = V_S (Z_0 \div (R_S + R_0 + Z_0))$$

 $Z_0 = 50\Omega \parallel 50\Omega$

 $R_S = 36\Omega || 36\Omega$

 $R_0 = 14\Omega$

$$V_L = 3.0 (25 \div (18+14+25)) = 1.31V$$

At the load end the voltage will double, due to the near unity reflection coefficient, to 2.5V. It will then increment towards the quiescent 3.0V in steps separated by one

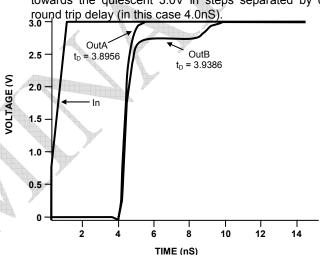


Figure 4. Single versus Dual Waveforms

Since this step is well above the threshold region it will not cause any false clock triggering, however designers may be uncomfortable with unwanted reflections on the line. To better match the impedances when driving multiple lines the situation in Figure 5. "Optimized Dual Line Termination" should be used. In this case the series terminating resistors are reduced such that when the parallel combination is added to the output buffer impedance the line impedance is perfectly matched.

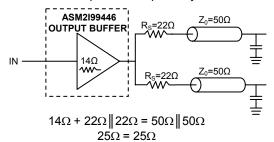


Figure 5. Optimized Dual Line Termination

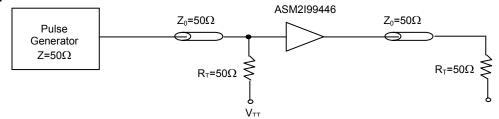


Figure 6. CCLK0, 1 ASM2I99446 AC test reference for V_{CC} = 3.3V and V_{CC} = 2.5V

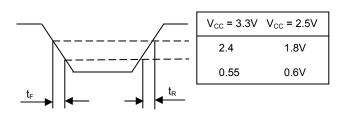
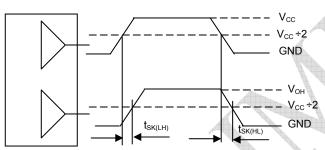
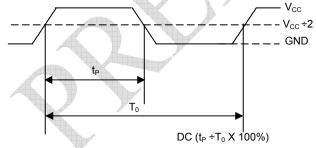


Figure 7. Output Transition Time Test Reference



The pin-to-pin skew is defined as the worst case difference in propagation delay between any similar delay path within a single device

Figure 9. Output-to-Output Skew t_{SK(LH.HL)}



The time from the PLL controlled edge to the non-controlled edge, divided by the time between PLL controlled edges, expressed as a percentage.

Figure 11. Output Duty Cycle (DC) Reference

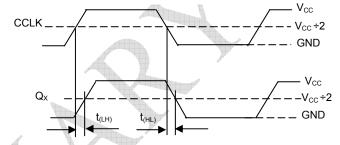


Figure 8. Propagation Delay (t_{PD}) Test Reference

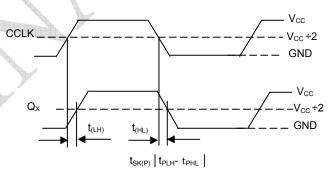
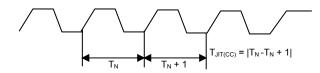


Figure 10. Propagation Delay (t_{SK(P)}) Test Reference



The variation in cycle time of a signal between adjacent cycles, over a random sample of adjacent cycle pairs

Figure 12. Cycle-to-Cycle Jitter

Power Consumption of the ASM2I99446 and Thermal Management

The ASM2I99446 AC specification is guaranteed for the entire operating frequency range up to 250MHz. The ASM2I99446 power consumption and the associated long-term reliability may decrease the maximum frequency limit, depending on operating conditions such as clock frequency, supply voltage, output loading, ambient temperature, vertical convection and thermal conductivity of package and board. This section describes the impact of these parameters on the junction temperature and gives a guideline to estimate the ASM2I99446 die junction temperature and the associated device reliability.

Table 11. Die junction temperature and MTBF

Junction temperature (°C)	MTBF (Years)
100	20.4
110	9.1
120	4.2
130	2.0

Increased power consumption will increase the die junction temperature and impact the device reliability (MTBF). According to the system-defined tolerable MTBF, the die junction temperature of the ASM2I99446 needs to be controlled and the thermal impedance of the board/package should be optimized. The power dissipated in the ASM2I99446 is represented in equation 1.

Where I_{CCQ} is the static current consumption of the ASM2I99446, C_{PD} is the power dissipation capacitance per output, $(M)\Sigma C_L$ represents the external capacitive output load, N is the number of active outputs (N is always 12 in case of the ASM2I99446). The ASM2I99446 supports driving transmission lines to maintain high signal integrity and tight timing parameters. Any transmission line will hide the lumped capacitive load at the end of the board trace, therefore, ΣC_L is zero for controlled transmission line systems and can be eliminated from equation 1. Using parallel termination output termination results in equation 2 for power dissipation.

In equation 2, P stands for the number of outputs with a parallel or thevenin termination, $V_{\text{OL}},\,I_{\text{OL}},\,V_{\text{OH}}$ and I_{OH} are a function of the output termination technique and DC $_{\text{Q}}$ is the clock signal duty cycle. If transmission lines are used ΣCL is zero in equation 2 and can be eliminated. In general, the use of controlled transmission line techniques eliminates the impact of the lumped capacitive loads at the end lines and greatly reduces the power dissipation of the device. Equation 3 describes the die junction temperature T_J as a function of the power consumption.

Where R_{thja} is the thermal impedance of the package (junction to ambient) and T_A is the ambient temperature. According to Table 11, the junction temperature can be used to estimate the long-term device reliability. Further, combining equation 1 and equation 2 results in a maximum operating frequency for the ASM2I99446 in a series terminated transmission line system, equation 4.

$$P_{\text{TOT}} = \left[I_{\text{CCQ}} + V_{\text{CC}} \cdot f_{\text{CLOCK}} \cdot \left(N \cdot C_{\text{PD}} + \sum_{M} C_{L} \right) \right] \cdot V_{\text{CC}}$$
 Equation 1

$$P_{TOT} = V_{CC} \cdot \left[I_{CCQ} + V_{CC} \cdot f_{CLOCK} \cdot \left(N \cdot C_{PD} + \sum_{M} C_L \right) \right] + \sum_{P} \left[DC_Q \cdot I_{OH} \cdot \left(V_{CC} - V_{OH} \right) + \left(1 - DC_Q \right) \cdot I_{OL} \cdot V_{OL} \right] Equation \ 2 + \sum_{M} \left[DC_Q \cdot I_{OH} \cdot \left(V_{CC} - V_{OH} \right) + \left(1 - DC_Q \right) \cdot I_{OL} \cdot V_{OL} \right] Equation \ 2 + \sum_{M} \left[DC_Q \cdot I_{OH} \cdot \left(V_{CC} - V_{OH} \right) + \left(1 - DC_Q \right) \cdot I_{OL} \cdot V_{OL} \right] Equation \ 2 + \sum_{M} \left[DC_Q \cdot I_{OH} \cdot \left(V_{CC} - V_{OH} \right) + \left(1 - DC_Q \right) \cdot I_{OL} \cdot V_{OL} \right] Equation \ 2 + \sum_{M} \left[DC_Q \cdot I_{OH} \cdot \left(V_{CC} - V_{OH} \right) + \left(1 - DC_Q \right) \cdot I_{OL} \cdot V_{OL} \right] Equation \ 2 + \sum_{M} \left[DC_Q \cdot I_{OH} \cdot \left(V_{CC} - V_{OH} \right) + \left(1 - DC_Q \right) \cdot I_{OL} \cdot V_{OL} \right] Equation \ 2 + \sum_{M} \left[DC_Q \cdot I_{OH} \cdot \left(V_{CC} - V_{OH} \right) + \left(1 - DC_Q \right) \cdot I_{OL} \cdot V_{OL} \right] Equation \ 2 + \sum_{M} \left[DC_Q \cdot I_{OH} \cdot \left(V_{CC} - V_{OH} \right) + \left(1 - DC_Q \right) \cdot I_{OL} \cdot V_{OL} \right] Equation \ 2 + \sum_{M} \left[DC_Q \cdot I_{OH} \cdot \left(V_{CC} - V_{OH} \right) + \left(1 - DC_Q \right) \cdot I_{OL} \cdot V_{OL} \right] Equation \ 2 + \sum_{M} \left[DC_Q \cdot I_{OH} \cdot \left(V_{CC} - V_{OH} \right) + \left(1 - DC_Q \right) \cdot I_{OL} \cdot V_{OL} \right] Equation \ 2 + \sum_{M} \left[DC_Q \cdot I_{OH} \cdot \left(V_{CC} - V_{OH} \right) + \left(1 - DC_Q \right) \cdot I_{OL} \cdot V_{OL} \right] Equation \ 2 + \sum_{M} \left[DC_Q \cdot I_{OH} \cdot \left(V_{CC} - V_{OH} \right) + \left(1 - DC_Q \right) \cdot I_{OL} \cdot V_{OL} \right] Equation \ 2 + \sum_{M} \left[DC_Q \cdot I_{OH} \cdot \left(V_{CC} - V_{OH} \right) + \left(1 - DC_Q \right) \right] Equation \ 2 + \sum_{M} \left[DC_Q \cdot I_{OH} \cdot \left(V_{CC} - V_{OH} \right) + \left(1 - DC_Q \right) \right] Equation \ 2 + \sum_{M} \left[DC_Q \cdot I_{OH} \cdot \left(V_{CC} - V_{OH} \right) + \left(1 - DC_Q \right) \right] Equation \ 2 + \sum_{M} \left[DC_Q \cdot I_{OH} \cdot \left(V_{CC} - V_{OH} \right) + \left(V_{CC} - V_{OH} \right) \right] Equation \ 2 + \sum_{M} \left[DC_Q \cdot I_{OH} \cdot \left(V_{CC} - V_{OH} \right) + \left(V_{CC} - V_{OH} \right) \right] Equation \ 2 + \sum_{M} \left[DC_Q \cdot I_{OH} \cdot \left(V_{CC} - V_{OH} \right) \right] Equation \ 2 + \sum_{M} \left[DC_Q \cdot I_{OH} \cdot V_{OC} \right] Equation \ 2 + \sum_{M} \left[DC_Q \cdot I_{OH} \cdot V_{OC} \right] Equation \ 2 + \sum_{M} \left[DC_Q \cdot I_{OH} \cdot V_{OC} \right] Equation \ 2 + \sum_{M} \left[DC_Q \cdot I_{OH} \cdot V_{OC} \right] Equation \ 2 + \sum_{M} \left[DC_Q \cdot I_{OH} \cdot V_{OC} \right] Equation \ 2 + \sum_{M} \left[DC_Q \cdot I_$$

$$T_{I} = T_{A} + P_{TOT} \cdot R_{thia}$$
 Equation 3

$$f_{\text{CLOCK,MAX}} = \frac{1}{C_{\text{PD}} \cdot N \cdot V_{\text{CC}}^2} \cdot \left[\frac{T_{\text{J,MAX}} - T_{\text{A}}}{R_{\text{thja}}} - \left(I_{\text{CCQ}} \cdot V_{\text{CC}} \right) \right]$$
 Equation 4

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 $T_{\rm J}$,MAX should be selected according to the MTBF system requirements and Table 11. $R_{\rm thja}$ can be derived from Table 12. The $R_{\rm thja}$ represent data based on 1S2P boards, using 2S2P boards will result in a lower thermal impedance than indicated below.

Table 12. Thermal package impedance of the 32LQFP

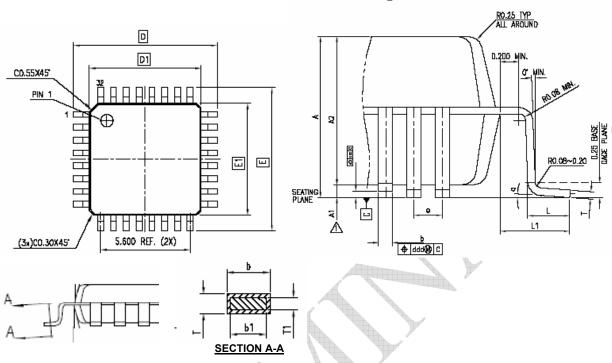
Convection, LFPM	R _{thja} (1P2S board), °C/W	R _{thja} (2P2S board), °C/W
Still air	86	61
100 lfpm	76	56
200 lfpm	71	54
300 lfpm	68	53
400 lfpm	66	52
500 Ifpm	60	49

If the calculated maximum frequency is below 350 MHz, it becomes the upper clock speed limit for the given application conditions. The following eight derating charts describe the safe frequency operation range for the ASM2I99446. The charts were calculated for a maximum tolerable die junction temperature of 110°C (120°C), corresponding to an estimated MTBF of 9.1 years (4 years), a supply voltage of 3.3V and series terminated transmission line or capacitive loading. Depending on a given set of these operating conditions and the available device convection a decision on the maximum operating frequency can be made.

rev 0.4

Package Information

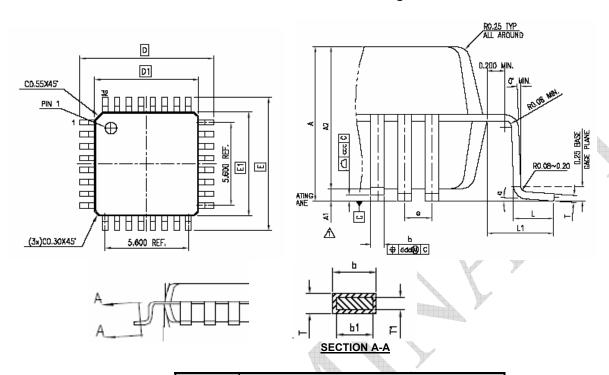
32-lead TQFP Package



	Dimensions				
Symbol	Inches		Millimeters		
	Min	Max	Min	Max	
Α		0.0472		1.2	
A1	0.0020	0.0059	0.05	0.15	
A2	0.0374	0.0413	0.95	1.05	
D	0.3465	0.3622	8.8	9.2	
D1	0.2717	0.2795	6.9	7.1	
E	0.3465	0.3622	8.8	9.2	
E1	0.2717	0.2795	6.9	7.1	
L	0.0177	0.0295	0.45	0.75	
L1	0.03937 REF		1.00 REF		
Т	0.0035	0.0079	0.09	0.2	
T1	0.0038	0.0062	0.097	0.157	
b	0.0118	0.0177	0.30	0.45	
b1	0.0118	0.0157	0.30	0.40	
R0	0.0031	0.0079	0.08	0.2	
а	0°	7°	0°	7°	
е	0.031 BASE		0.8 BASE		

rev 0.4

32-lead LQFP Package



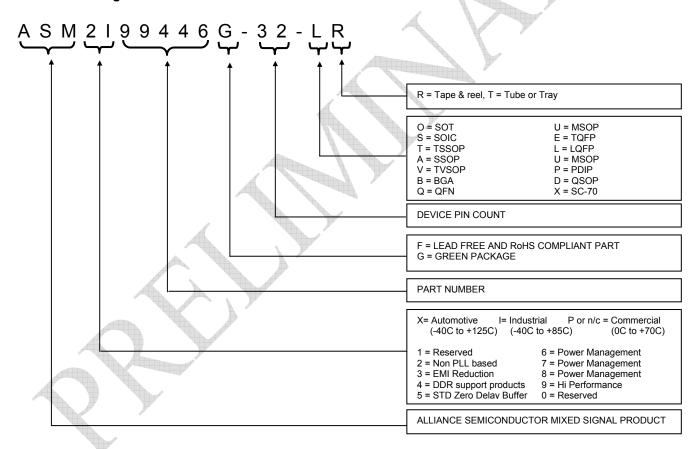
	Dimensions				
Symbol	mbol Inches		Millimeters		
	Min	Max	Min	Max	
Α		0.0630		1.6	
A1	0.0020	0.0059	0.05	0.15	
A2	0.0531	0.0571	1.35	1.45	
D	0.3465	0.3622	8.8	9.2	
D1	0.2717	0.2795	6.9	7.1	
E	0.3465	0.3622	8.8	9.2	
E1_	0.2717	0.2795	6.9	7.1	
L	0.0177	0.0295	0.45	0.75	
L1	0.03937 REF		1.00 REF		
Т	0.0035	0.0079	0.09	0.2	
T1	0.0038	0.0062	0.097	0.157	
b	0.0118	0.0177	0.30	0.45	
b1	0.0118	0.0157	0.30	0.40	
R0	0.0031	0.0079	0.08	0.20	
е	0.031 BASE		0.8 BASE		
а	0°	7°	0°	7°	

July 2005

Ordering Information

Part Number	Marking	Package Type	Operating Range
ASM2I99446-32-LT	ASM2I99446L	32-pin LQFP, Tray	Industrial
ASM2I99446-32-LR	ASM2I99446L	32-pin LQFP,Tape and Reel	Industrial
ASM2I99446G-32-LT	ASM2I99446GL	32-pin LQFP, Tray, Green	Industrial
ASM2I99446G-32-LR	ASM2I99446GL	32-pin LQFP, Tape and Reel, Green	Industrial
ASM2I99446-32-ET	ASM2I99446E	32-pin TQFP, Tray	Industrial
ASM2I99446-32-ER	ASM2I99446E	32-pin TQFP,Tape and Reel	Industrial
ASM2I99446G-32-ET	ASM2I99446GE	32-pin TQFP, Tray, Green	Industrial
ASM2I99446G-32-ER	ASM2I99446GE	32-pin TQFP,Tape and Reel, Green	Industrial

Device Ordering Information



Licensed under US patent #5,488,627, #6,646,463 and #5,631,920.



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Note: This product utilizes US Patent #6,646,463 Impedance Emulator Patent issued to Alliance Semiconductor, dated 11-11-2003

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